



Driver Applications

Applications

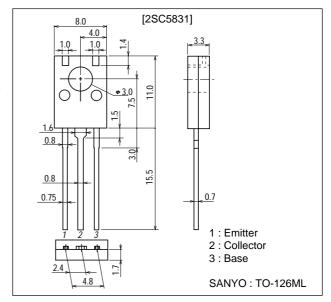
• Suitable for use in switching of inductive load (motor drivers, printer hammer drivers, relay drivers).

Features

- · High DC current gain.
- · Wide ASO.
- On-chip zener diode of 65±10V between collector and base.
- · Uniformity in collector-to-base voltage.
- · Large inductive load handling capability.

Package Dimensions

unit : mm 2042B



Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	VCBO		*55	V
Collector-to-Emitter Voltage	VCEO		*55	V
Emitter-to-Base Voltage	VEBO		6	V
Collector Current	IC		2	Α
Collector Current (Pulse)	ICP		4	Α
Collector Dissipation	D-		1.5	W
	PC	Tc=25°C	10	W
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

^{*:} On-chip zener diode(65±10V)

Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Oill
Collector Cutoff Current	ICBO	V _{CB} =40V, I _E =0			10	μΑ
Emitter Cutoff Current	IEBO	V _{EB} =5V, I _C =0			2	mA

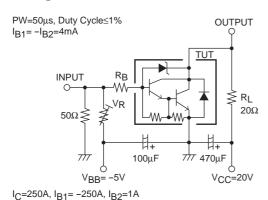
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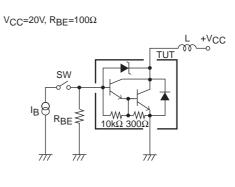
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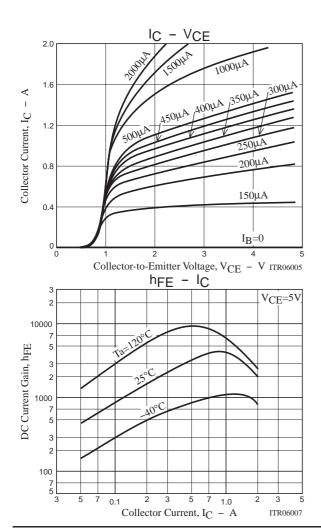
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Offic
DC Current Gain	hFE	V _{CE} =5V, I _C =1A	1000	4000		
Gain-Bandwidth Product	fT	V _{CE} =5V, I _C =1A		180		MHz
Inductive Load	Es/b	L=100mH, RBE=100Ω	25			mJ
Collector-to-Emitter Saturation Voltage	V _{CE} (sat)	I _C =1A, I _B =4mA		1.0	1.5	V
Base-to-Emitter Saturation Voltage	V _{BE} (sat)	I _C =1A, I _B =4mA			2.0	V
Collector-to-Base Breakdown Voltage	V(BR)CBO	IC=100μA, IE=0	55	65	75	V
Collector-to-Emitter Breakdown Voltage	V(BR)CEO	IC=1mA, RBE=∞	55	65	75	V
Turn-ON Time	ton	See specified Test Circuit.		0.2		μs
Storage Time	t _{stg}	See specified Test Circuit.		3.5		μs
Fall Time	tf	See specified Test Circuit.		0.5		μs

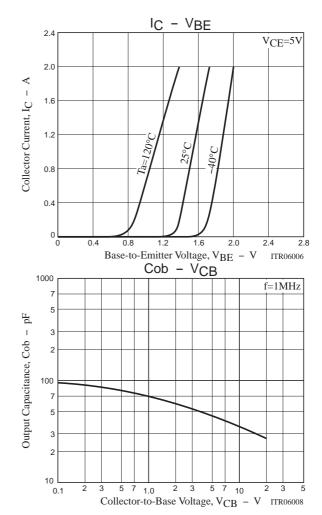
Switching Time Test Circuit



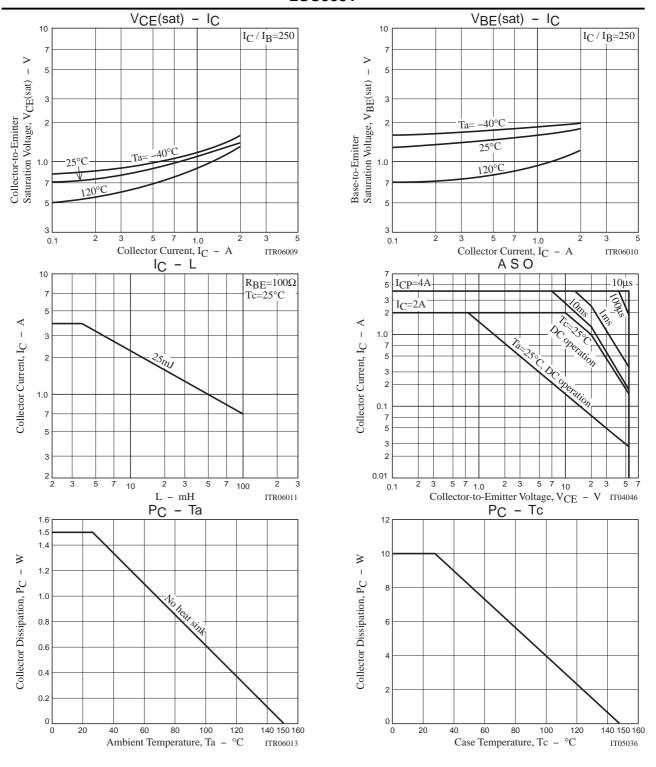
Es / b Test Circuit







2SC5831



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